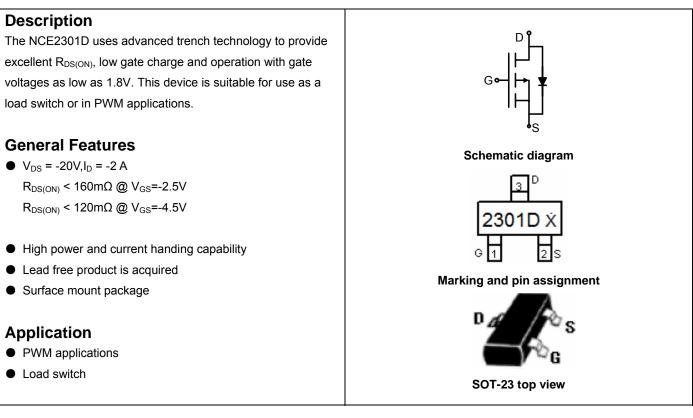


# NCE P-Channel Enhancement Mode Power MOSFET



### Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301D X	NCE2301D	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings (T<sub>A</sub>=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	Vds	-20	V	
Gate-Source Voltage	Vgs	±12	V	
Drain Current-Continuous	I <sub>D</sub>	-2.0	A	
Drain Current -Pulsed (Note 1)	I <sub>DM</sub>	-10	A	
Maximum Power Dissipation	PD	0.7	W	
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C	

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	178	°C/W
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#### Electrical Characteristics (T<sub>A</sub>=25<sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250µA	-20		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-20V, $V_{GS}$ =0V	-	-	-1	μA





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Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±12V, $V_{DS}$ =0V	-	-	±100	nA
On Characteristics (Note 3)						•
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
Drain Courses On State Desistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2 A	-	102	135	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-1.8A	-	140	170	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =-5V,I <sub>D</sub> =-2A	4	-	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C <sub>lss</sub>		-	290	-	PF
Output Capacitance	Coss	$V_{DS}$ =-10V, $V_{GS}$ =0V,	-	60	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	34	-	PF
Switching Characteristics (Note 4)						•
Turn-on Delay Time	t <sub>d(on)</sub>		-	10	-	nS
Turn-on Rise Time	tr	V <sub>DD</sub> =-10V, R <sub>L</sub> =5Ω V <sub>GS</sub> =-4.5V,R <sub>GEN</sub> =3Ω	-	5.0	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	21	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	7	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =-10V,I <sub>D</sub> =-2A, V <sub>GS</sub> =-4.5V	-	3.0	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	0.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	0.8	_	nC
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-2A	-	-	-1.2	V
Diode Forward Current (Note 2)	I <sub>S</sub>		-	-	-2.0	А

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



NCE2301D



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# **Typical Electrical and Thermal Characteristics**

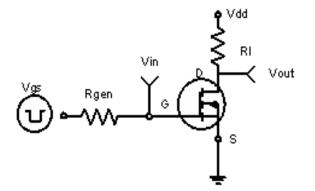
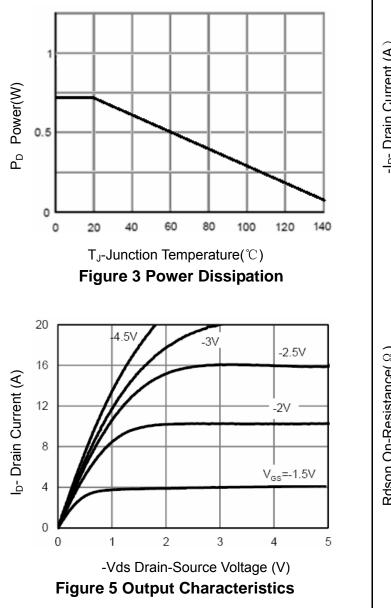
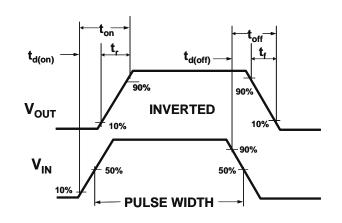
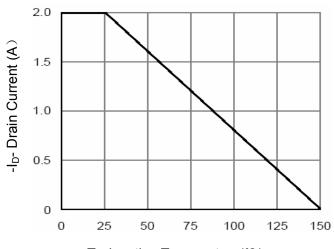


Figure 1:Switching Test Circuit

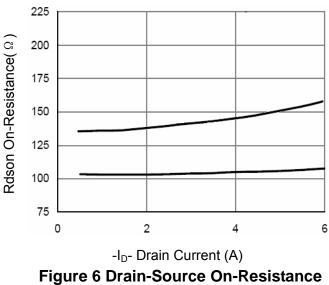








T<sub>J</sub>-Junction Temperature(℃) Figure 4 Drain Current



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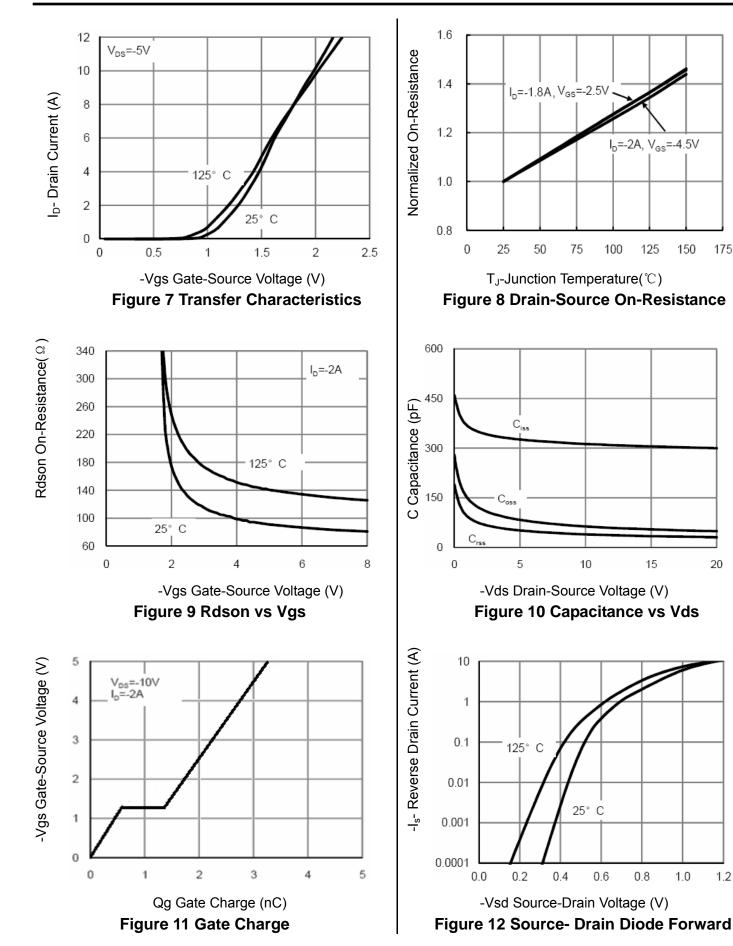


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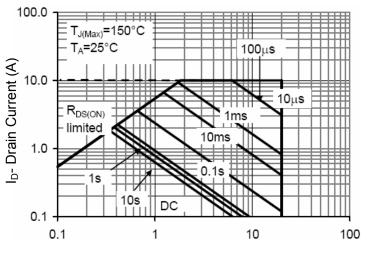
1.2



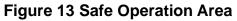








Vds Drain-Source Voltage (V)



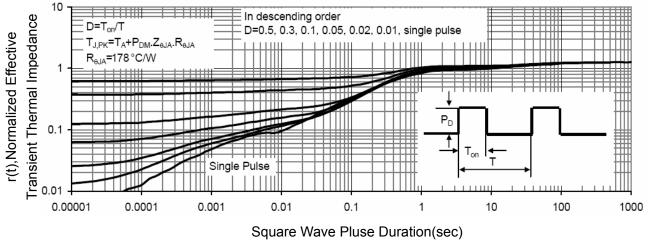
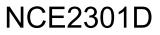
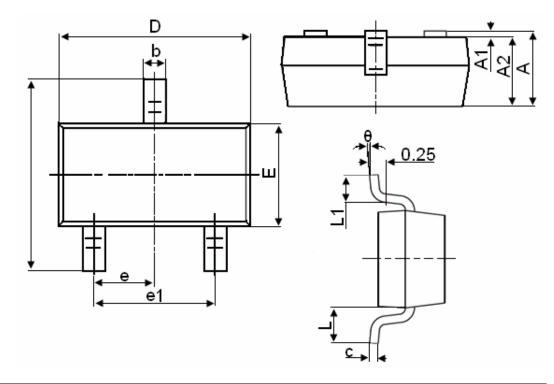


Figure 14 Normalized Maximum Transient Thermal Impedance





# **SOT-23 Package Information**



Symbol	Dimensions in Millimeters		
Symbol	MIN.	MAX.	
A	0.900	1.150	
A1	0.000	0.100	
A2	0.900	1.050	
b	0.300	0.500	
с	0.080	0.150	
D	2.800	3.000	
E	1.200	1.400	
E1	2.250	2.550	
е	0.950TYP		
e1	1.800	2.000	
L		0.550REF	
L1	0.300	0.500	
θ	0°	8°	

#### Notes

1. All dimensions are in millimeters.

2. Tolerance ±0.10mm (4 mil) unless otherwise specified

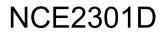
3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.

4. Dimension L is measured in gauge plane.

5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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